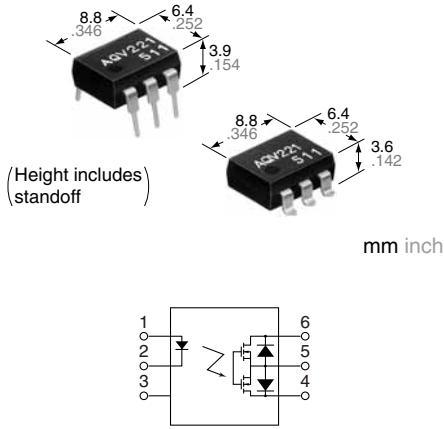




1 Form A type Radio frequent switching

PhotoMOS®

RF 1 Form A
(AQV22O)



FEATURES

1. High frequency characteristics with low capacitance between output terminals

Low output capacitance: typ. 4.8 pF
Isolation loss: 40 dB or more (at 1 MHz)
(AQV225)

2. High speed switching

Turn on time: typ. 0.1 ms
Turn off time: typ. 0.03 ms

3. Low-level off state leakage current of typ. 0.03 nA

4. Controls low-level analog signals

PhotoMOS® features extremely low closed-circuit offset voltages to enable control of small analog signals without distortion.

TYPICAL APPLICATIONS

1. Measuring instruments

Scanner, IC checker, Board tester, etc.

2. Audio visual equipment

CD, VCR

3. Security equipment

RoHS compliant

TYPES

Load voltage	Load current	Package	Part No.				Packing quantity	
			Through hole terminal		Surface-mount terminal			
			Tube packing style		Tape and reel packing style			
AC/DC dual use	40 V	DIP6-pin	AQV221	AQV221A	AQV221AX	AQV221AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	
	80 V		AQV225	AQV225A	AQV225AX	AQV225AZ		

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV221(A)	AQV225(A)	Remarks
Input	LED forward current	I _F	A	50 mA		
	LED reverse voltage	V _R		5 V		
	Peak forward current	I _{FP}		1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75 mW		
Output	Load voltage (peak AC)	V _L	A	40 V	80 V	
	Continuous load current	I _L		0.08 A	0.05 A	A connection: Peak AC, DC B, C connection: DC
	Peak load current	I _{peak}		0.09 A	0.06 A	
	Power dissipation	P _{out}	C	0.12 A	0.075 A	
	Total power dissipation	P _T		0.18 A	0.15 A	A connection: 100 ms (1 shot), V _L = DC
I/O isolation voltage		V _{iso}		230 mW		
Temperature limits	Operating	T _{opr}		280 mW		
	Storage	T _{stg}		1,500 V AC		Non-condensing at low temperatures
				-40°C to +85°C -40°F to +185°F		
				-40°C to +100°C -40°F to +212°F		

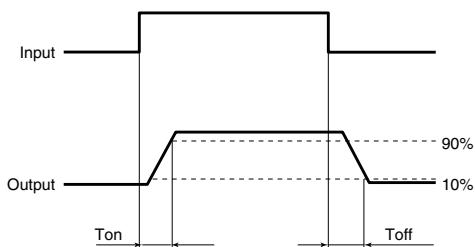
RF 1 Form A (AQV22O)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV221(A)	AQV225(A)	Remarks
Input	LED operate current	Typical	I_{Fon}	—	0.9 mA	$I_L = \text{Max.}$
		Maximum			3 mA	
	LED turn off current	Minimum	I_{Foff}	—	0.4 mA	$I_L = \text{Max.}$
		Typical			0.85 mA	
	LED dropout voltage	Typical	V_F	—	1.25 V (1.14 V at $I_F = 5 \text{ mA}$)	$I_F = 50 \text{ mA}$
		Maximum			1.5 V	
Output	On resistance	Typical	R_{on}	A	22 Ω	—
		Maximum			35 Ω	—
		Typical	R_{on}	B	13 Ω	—
		Maximum			18 Ω	—
		Typical	R_{on}	C	6.5 Ω	—
		Maximum			9 Ω	—
	Output capacitance	Typical	C_{out}	—	5.6 pF	—
		Maximum			8 pF	—
	Off state leakage current	Typical	I_{Leak}	—	0.03 nA	—
		Maximum			10 nA (1 nA or less)*	—
Transfer characteristics	Turn on time**	Typical	T_{on}	—	0.1 ms	—
		Maximum			0.3 ms	—
	Turn off time**	Typical	T_{off}	—	0.03 ms	—
		Maximum			0.1 ms	—
	I/O capacitance	Typical	C_{iso}	—	0.8 pF	—
		Maximum			1.5 pF	—
	Initial I/O isolation resistance	Minimum	R_{iso}	—	1,000 MΩ	500 V DC

*Available as custom orders (1 nA or less)

**Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	5	mA

■ These products are not designed for automotive use.

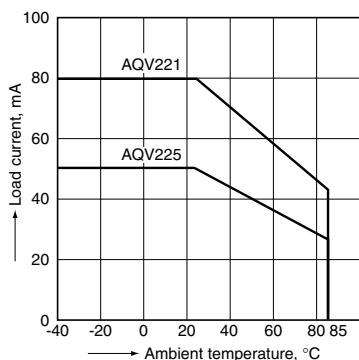
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

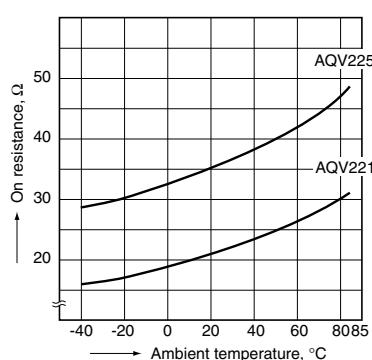
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$

Type of connection: A



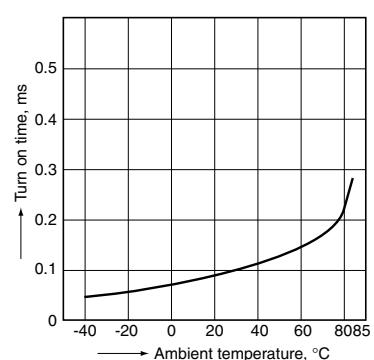
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
 LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



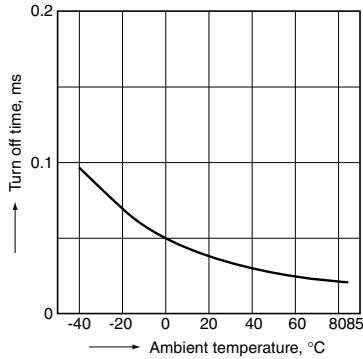
3. Turn on time vs. ambient temperature characteristics

Sample: AQV221, AQV225; LED current: 5 mA;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



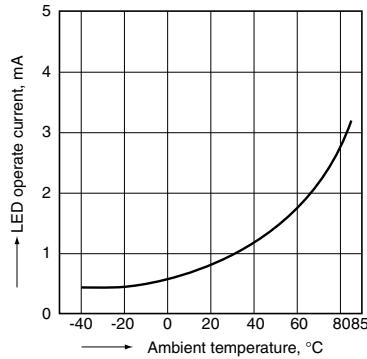
4. Turn off time vs. ambient temperature characteristics

Sample: AQV221, AQV225; LED current: 5 mA;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



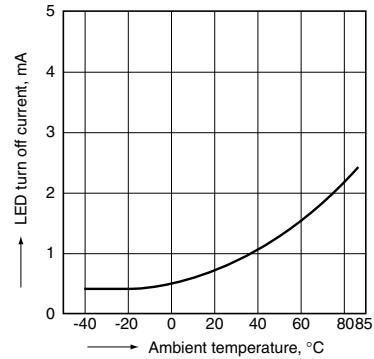
5. LED operate current vs. ambient temperature characteristics

Sample: AQV221, AQV225;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



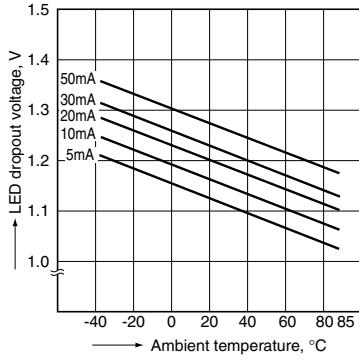
6. LED turn off current vs. ambient temperature characteristics

Sample: AQV221, AQV225;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



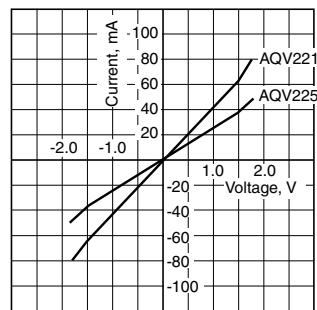
7. LED dropout voltage vs. ambient temperature characteristics

Sample: AQV221, AQV225;
 LED current: 5 to 50 mA



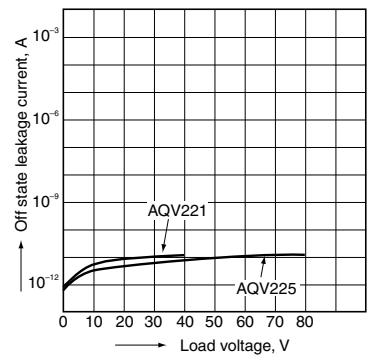
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



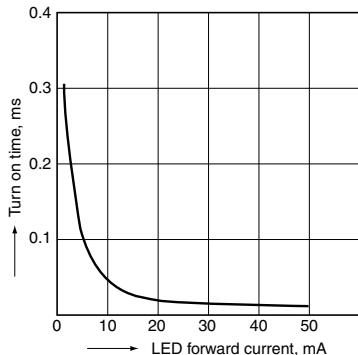
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F

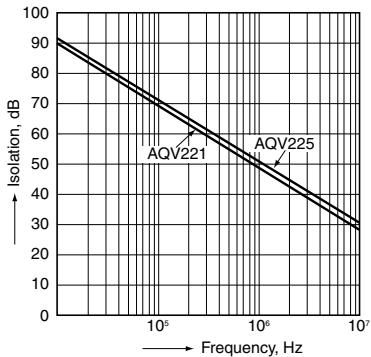


RF 1 Form A (AQV22O)

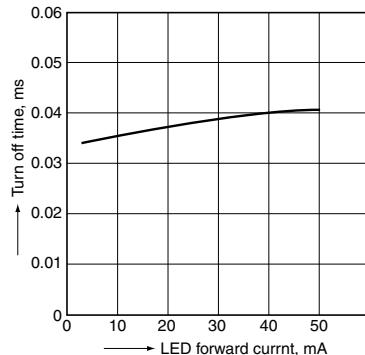
10. Turn on time vs. LED forward current characteristics
Sample: AQV221, AQV225;
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



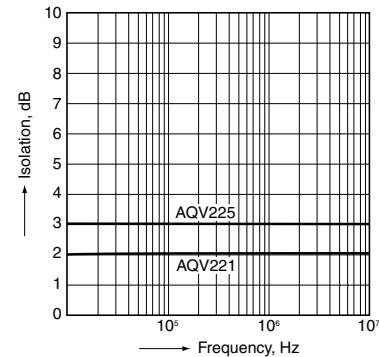
13. Isolation vs. frequency characteristics (50Ω impedance)
Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics
Sample: AQV221, AQV225;
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



14. Insertion loss vs. frequency characteristics (50Ω impedance)
Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics
Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

